

PS2501-1X, PS2501-2X, PS2501-4X
 PS2501-1, PS2501-2, PS2501-4



**HIGH DENSITY MOUNTING
 PHOTOTRANSISTOR
 OPTICALLY COUPLED ISOLATORS**

APPROVALS

- UL recognised, File No. E91231
- 'X' SPECIFICATION APPROVALS
- VDE 0884 in 3 available lead form : -
 - STD
 - G form
 - SMD approved to CECC 00802
- Certified to EN60950 by the following
 Test Bodies :-
 Nemko - Certificate No. P01102465
 Fimko - Certificate No. FI18162
 Semko - Reference No. 0202041/01-25
 Demko - Certificate No. 311161-01
- BSI approved - Certificate No. 8001

DESCRIPTION

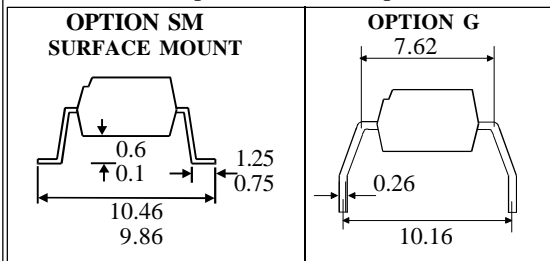
The PS2501-1, PS2501-2, PS2501-4 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

FEATURES

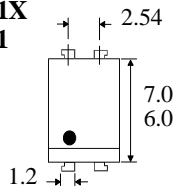
- Options :-
 10mm lead spread - add G after part no.
 Surface mount - add SM after part no.
 Tape & reel - add SMT&R after part no.
- High Current Transfer Ratio (80% min)
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- High BV_{CEO} (80Vmin)
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

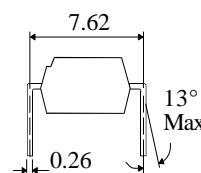
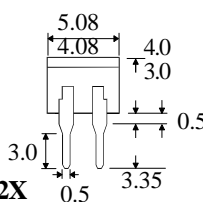
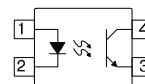
- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



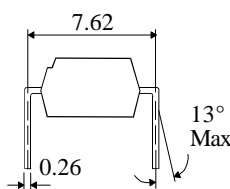
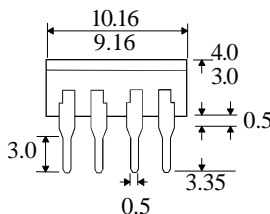
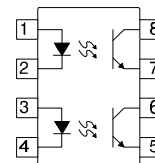
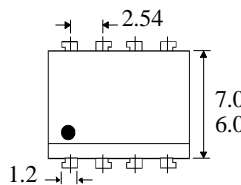
**PS2501-1X
 PS2501-1**



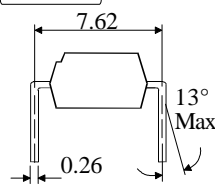
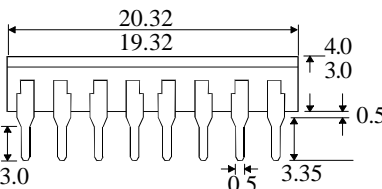
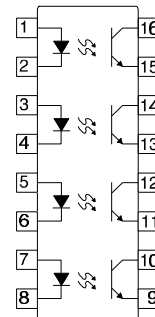
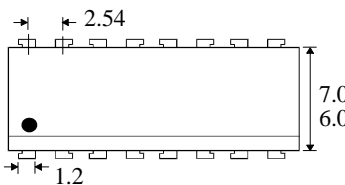
Dimensions in mm



**PS2501-2X
 PS2501-2**



**PS2501-4X
 PS2501-4**



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ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-55°C to + 125°C
Operating Temperature	-30°C to +100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	80V
Emitter-collector Voltage BV_{ECO}	6V
Power Dissipation	150mW

POWER DISSIPATION

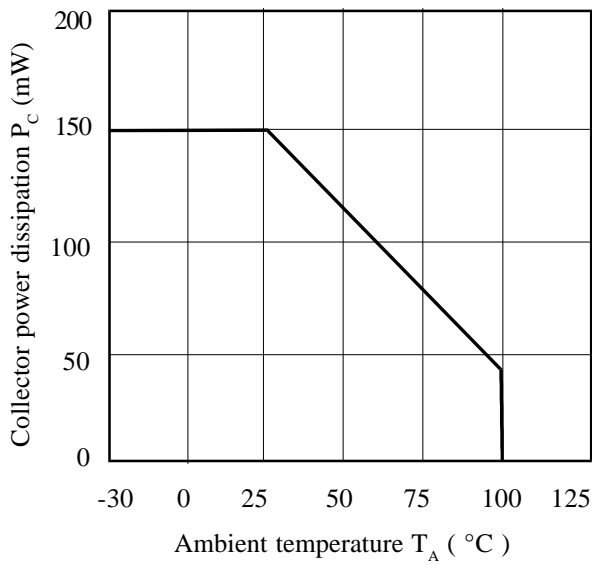
Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

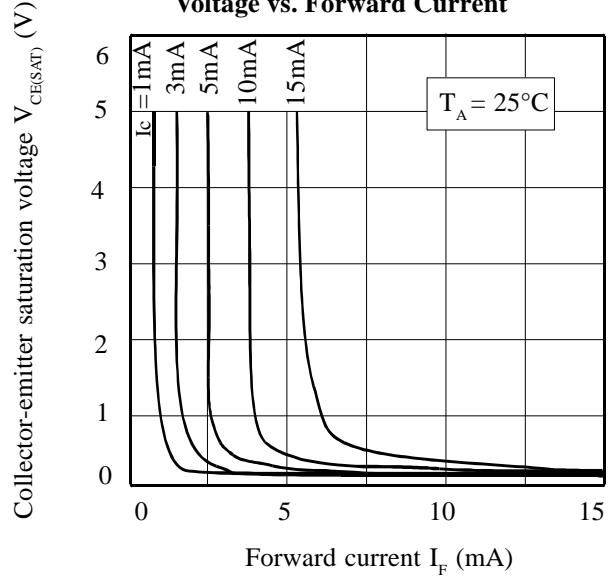
PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.4	V	$I_F = 20\text{mA}$
	Reverse Current (I_R)			10	μA	$V_R = 4\text{V}$
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	80			V	$I_C = 1\text{mA}$
	Emitter-collector Breakdown (BV_{ECO})	6			V	$I_E = 100\mu\text{A}$
	Collector-emitter Dark Current (I_{CEO})			100	nA	$V_{CE} = 20\text{V}$
Coupled	Current Transfer Ratio (CTR) (Note 2) PS2501-1,PS2501-2,PS2501-4 GR	80 100		600 300	% %	$5\text{mA } I_F, 5\text{V } V_{CE}$ $5\text{mA } I_F, 5\text{V } V_{CE}$
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$			0.3	V	$10\text{mA } I_F, 2\text{mA } I_C$
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500\text{V}$ (note 1)
	Output Rise Time tr		4		μs	$V_{CE} = 2\text{V},$
	Output Fall Time tf		3		μs	$I_C = 2\text{mA}, R_L = 100\Omega$

- Note 1 Measured with input leads shorted together and output leads shorted together.
Note 2 Special Selections are available on request. Please consult the factory.

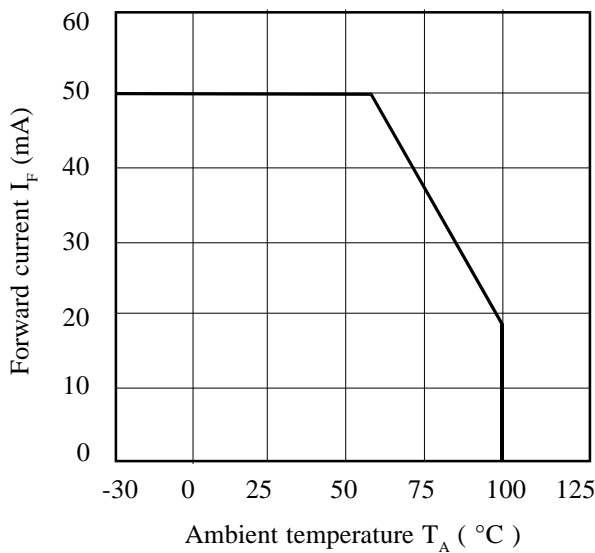
Collector Power Dissipation vs. Ambient Temperature



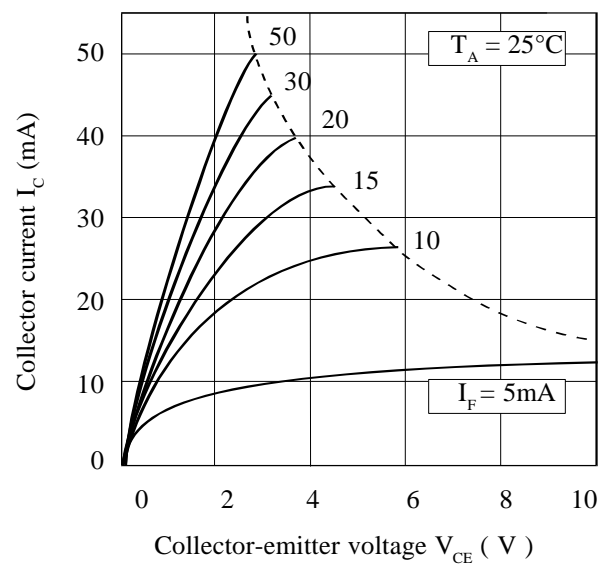
Collector-emitter Saturation Voltage vs. Forward Current



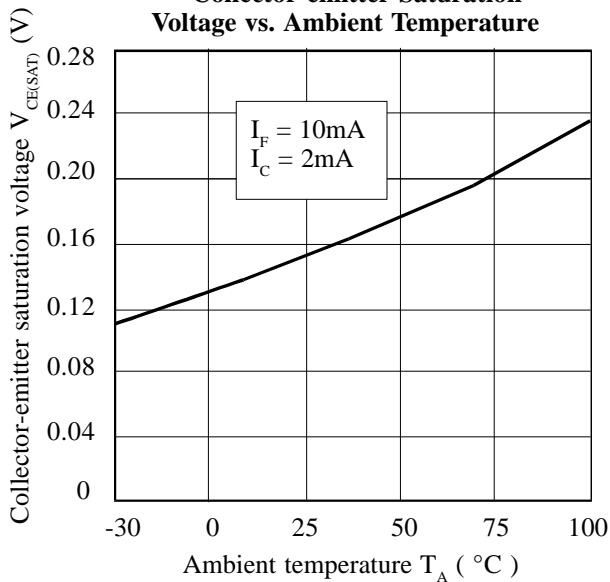
Forward Current vs. Ambient Temperature



Collector Current vs. Collector-emitter Voltage



Collector-emitter Saturation Voltage vs. Ambient Temperature



Current Transfer Ratio vs. Forward Current

